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## Gate dependence of upper critical field in superconducting (110) LaAlO<sub>3</sub>/SrTiO<sub>3</sub> interface

S. C. Shen<sup>1</sup>, B. B. Chen<sup>2</sup>, H. X. Xue<sup>1</sup>, G. Cao<sup>2</sup>, C. J. Li<sup>1</sup>, X. X. Wang<sup>1</sup>, Y. P. Hong<sup>1</sup>, G. P. Guo<sup>2</sup>, R. F. Dou<sup>1</sup>, C. M. Xiong<sup>1</sup>, L. He<sup>1</sup> & J. C. Nie<sup>1</sup>

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The fundamental parameters of the superconducting state such as coherence length and pairing strength are essential for understanding the nature of superconductivity. These parameters can be estimated by measuring critical parameters such as upper critical field,  $H_{c2}$ . In this work,  $H_{c2}$  of a superconducting (110) LaAlO<sub>3</sub>/SrTiO<sub>3</sub> interface is determined through magnetoresistive measurements as a function of the gate voltage,  $V_G$ . When  $V_G$  increases, the critical temperature has a dome-like shape, while  $H_{c2}$  monotonically decreases. This relationship of independence between the variation of  $T_c$  and of  $H_{c2}$  suggests that the Cooper pairing potential is stronger in the underdoped region and the coherence length increases with the increase of  $V_G$ . The result is as for high temperature superconducting cuprates and it is different than for conventional low temperature superconductors.

Oxide heterostructures have attracted much attention in recent years due to a plethora of novel or enhanced physical phenomena observed at interfaces<sup>1,2</sup>. For example, the *two dimensional electron gas* (2DEG) formed at the interface between two perovskite insulators, LaAlO<sub>3</sub> (LAO) and SrTiO<sub>3</sub> (STO), becomes superconducting<sup>3</sup> at around 200 mK. This discovery triggered intense investigations of the superconductivity mechanism<sup>4–8</sup> at interfaces. A number of intriguing properties emerge at the superconducting interface. Literature indicate on a pseudogap-like behavior<sup>9</sup>, on the electron pre-formed pairing<sup>10</sup>, and on the coexistence of superconductivity and ferromagnetism<sup>11–13</sup>. The phase diagram for an interface is similar to that of high temperature superconducting (HTS) cuprates<sup>7,9</sup>. The interface exhibits superconductivity for an extremely low carrier density<sup>14,15</sup>. Presented aspects may indicate on unconventional pairing mechanism. Nevertheless, the conventional electron-phonon coupling has been also considered<sup>5,16</sup>. Therefore, the microscopic mechanism responsible for interface superconductivity is still unclear and more research is of high interest.

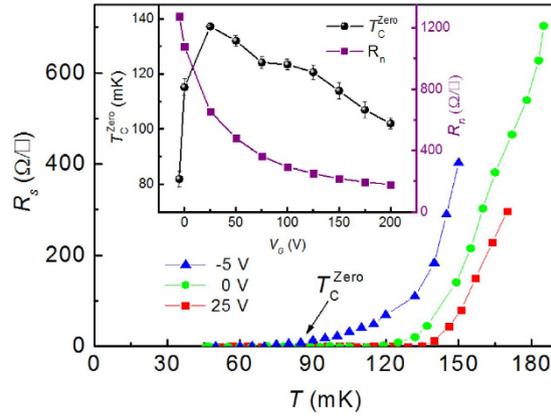
Recently, it was reported that an energy gap persists above the superconducting dome defined as the variation of the critical temperature,  $T_c$ , vs. carrier doping. Furthermore, the energy gap increases monotonically as the gate voltage  $V_G$  decreases. This correlation indicates on a pseudogap-like behavior of (001) LAO/STO interfaces<sup>9</sup> and it is opposite to the  $V_G$  dependence of the superfluid density<sup>14</sup>. For additional information about electron pairing in interfaces, it is useful to determine fundamental superconducting parameters such as the coherence length,  $\xi_0$ , and the strength of pairing potential. These parameters can be extracted from upper critical field,  $H_{c2}$ ; a higher  $H_{c2}$  means a smaller coherence length and a stronger pairing potential<sup>17</sup>. Previous investigations of  $H_{c2}$  have shown that superconductivity observed for (001) or (110) LAO/STO interfaces is of two dimensional nature<sup>3,18–20</sup>, but the  $V_G$  dependence of  $H_{c2}$  that is associated to pairing strength while being distinct from the superfluid density, has not been reported. Noteworthy is also that most studies are focused on (001) LAO/STO, while the (110) system is less explored although its study can bring an important contribution to understanding of superconductivity at interfaces<sup>20–22</sup>.

In this work we report the dependence of  $H_{c2}$  on  $V_G$  in a superconducting 2DEG (110) LAO/STO interface. We found that  $H_{c2}$  decreases when  $V_G$  increases. At the same time, the  $T_c(V_G)$  curve shows a dome-like shape (with a maximum). Our results indicate that the Cooper pairing potential becomes stronger in the underdoped regime.

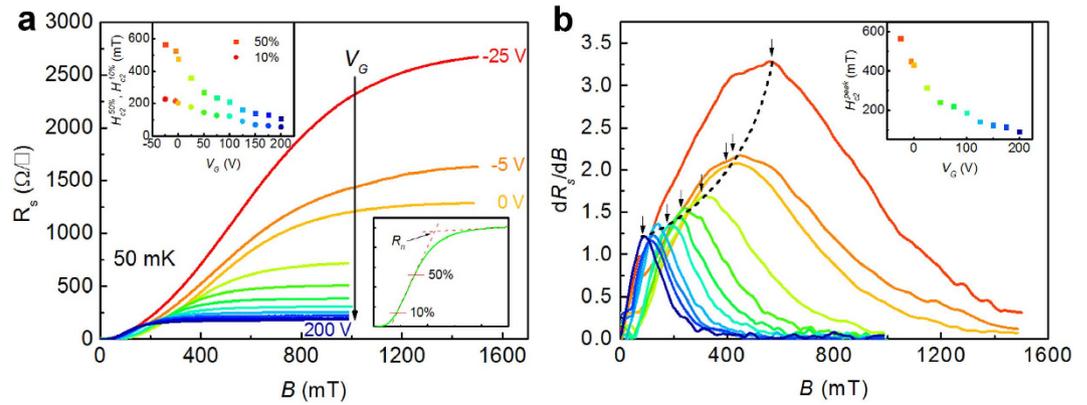
### Results and Discussions

**Critical temperature, critical current and normal state resistance as a function of gate voltage.** In Fig. 1 are presented as examples, curves of (interface or sheet) resistance,  $R_s$ , versus temperature for three

<sup>1</sup>Department of Physics, Beijing Normal University, Beijing 100875, China. <sup>2</sup>Key Laboratory of Quantum Information, CAS, University of Science and Technology of China, Hefei, Anhui 230026, China. Correspondence and requests for materials should be addressed to G.P.G. (email: gpguo@ustc.edu.cn) or J.C.N. (email: jcnie@bnu.edu.cn)



**Figure 1.** The resistance  $R_s$  of the (110) LAO/STO interface as a function of temperature at three representative gate voltages and for  $B = 0$  T. The inset shows the gate voltage  $V_G$  dependence of the critical temperature  $T_C^{Zero}$  and of the normal state resistance  $R_n$ . The maximum of the  $T_C^{Zero}(V_G)$  curve is at 138 mK and at 25 V. Lines are guide to the eyes.



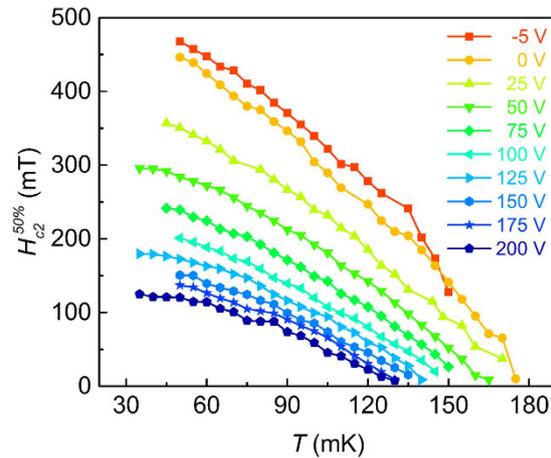
**Figure 2.** (a) Curves of  $R_s(B)$  for  $-5 \leq V_G \leq 200$  V at 50 mK. The inset in the right corner shows determination of  $R_n$ ,  $H_{c2}^{50\%}$  and  $H_{c2}^{10\%}$ . The inset in the left corner shows  $H_{c2}^{50\%}(V_G)$  and  $H_{c2}^{10\%}(V_G)$  curves at 50 mK; (b) Curves of  $dR_s/dB$  vs.  $B$  at 50 mK. Arrows indicate points of maximum of these curves and dashed line is guide for eyes. Magnetic field of a maximum point is defined as  $H_{c2}^{peak}$ . The inset shows variation of  $H_{c2}^{peak}$  as a function of  $V_G$ .

different gate voltages ( $-5$  V,  $0$  V and  $25$  V) under zero magnetic field. Temperature for which  $R_s$  drops below the detection limit of the measuring equipment defines the critical temperature,  $T_C^{Zero}$  (Fig. 1). The curve of  $T_C^{Zero}$  as a function of  $V_G$  (in zero magnetic field) has a dome-like shape with a maximum at  $25$  V (Fig. 1 inset). The dome-like shape of the  $T_C^{Zero}(V_G)$  curves was previously observed in LAO/STO and (001) LaTiO<sub>3</sub>/SrTiO<sub>3</sub> (LTO/STO) interfaces<sup>7,20,23</sup>. A dome-like shape with a maximum at  $V_G = 25$  V is also obtained for the variation of the critical current  $I_c(V_G)$ . The critical current,  $I_c$ , was determined at 50 mK from  $I$ - $V$  curves measurements (see Supplementary Information, Fig. S1). The  $T_C^{Zero}(V_G)$  and  $I_c(V_G)$  similar dome-like dependencies indicate a strong influence of the carrier density on  $T_C^{Zero}$  and  $I_c$ .

From the measurements of  $R_s$  with magnetic field (up to 1.6 T) applied perpendicular to the surface of the interface at a fixed temperature and gate voltage one can determine the normal state resistance,  $R_n$ . An example of  $R_s(B)$  curves at 50 mK and for  $V_G$  from  $-25$  to  $+200$  V is presented in Fig. 2a. Inset to Fig. 2a shows for selected ( $T, V_G$ ) values how  $R_n$  is determined. Namely,  $R_n$  is the resistance of the cross point between the fitting lines of the steepest part of the  $R_s(B)$  experimental curve and of the region where  $R_s$  almost saturates. For a fixed temperature (50 mK), one  $R_n(V_G)$  curve is plotted in Fig. 1 inset. Enhancement of  $V_G$  decreases  $R_n$ . Curve is non-linear and the decrease rate is smaller for higher  $V_G$ .

It is remarkable that  $V_G$  can tune superconducting and normal state characteristics such as  $T_C^{Zero}$  and  $R_n$ , respectively. Results suggest that  $V_G$  influences 2DEG superconductivity features and the carrier density. Our results are consistent with literature<sup>20</sup>.

**Upper critical field as a function of gate voltage.** For a fixed temperature and  $V_G$ , the upper critical field  $H_{c2}$  is determined as the field where resistance is 10%, 50% of  $R_n$  in the  $R_s(B)$  curves (Fig. 2a inset, right corner). This methodology was used to determine  $H_{c2}$  for different superconducting systems<sup>24–26</sup>. We note that magnetic field  $B$  is applied in this work only perpendicular to the interface surface. Reported articles<sup>19,20</sup> indicate that



**Figure 3.** Temperature dependence of  $H_{c2}^{50\%}$  for different  $V_G$ . Lines are guide for the eyes.

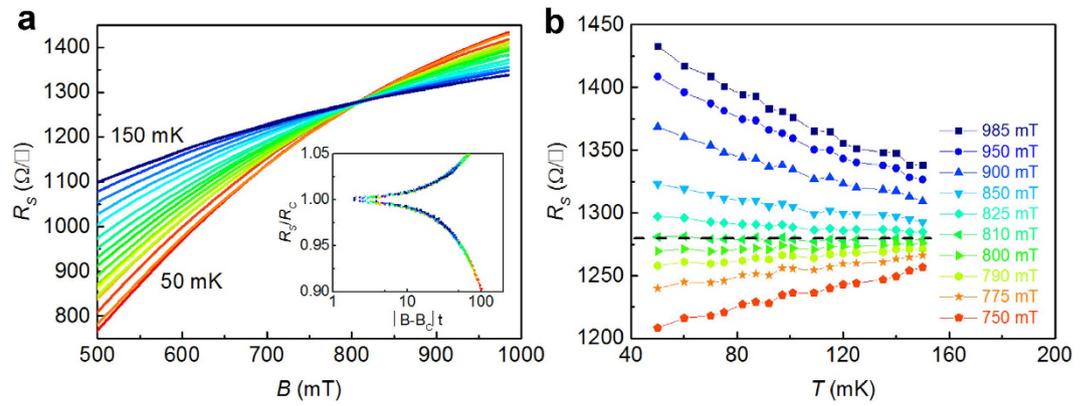
$H_{c2}$  shows large anisotropy when  $B$  is applied in-plane and out-of-plane. At 50 mK, the  $H_{c2}^{10\%}(V_G)$  or  $H_{c2}^{50\%}(V_G)$  (Fig. 2 inset, left corner) curves are unexpectedly without a dome-like shape that is specific for the  $T_C^{Zero}(V_G)$  and  $I_c(V_G)$  (Figs 1 and S1) curves. Namely, for a lower  $V_G$ ,  $H_{c2}$  monotonically increases (Fig. 2 inset, left corner). At the same time, a decrease of  $V_G$  below  $V_{G, \max} = 25$  V counter-intuitively produces the decrease of both  $T_C^{Zero}$  and  $I_c$  (Figs 1 and S1).

The differential curves  $dR_s/dB$  as a function of  $B$ , obtained from  $R_s(B)$  data (Fig. 2a) for different  $V_G$  and at 50 mK, are presented in Fig. 2b. Each curve displays a peak (marked with an arrow in Fig. 2b). The peak shifts to higher  $B$  and its intensity increases when  $V_G$  decreases. The magnetic field of the peak, denoted  $H_{c2}^{peak}$ , as a function of  $V_G$  (at 50 mK) is shown in Fig. 2b, inset. A dome-like shape is not obtained and, as expected, this curve has a similar behavior as  $H_{c2}^{10\%}(V_G)$  or  $H_{c2}^{50\%}(V_G)$  curves. Furthermore, the values of  $H_{c2}^{peak}$  and of  $H_{c2}^{50\%}$  are close to each other, but we shall keep both parameters in the discussion because of their different background:  $H_{c2}^{50\%}$  is arbitrary taken, while  $H_{c2}^{peak}$  defines the inflexion point of the  $R_s(B)$  cur. The inflexion point may have a physical meaning and, hence,  $H_{c2}^{peak}$  can be more sensitive to external factors than  $H_{c2}^{50\%}$ .

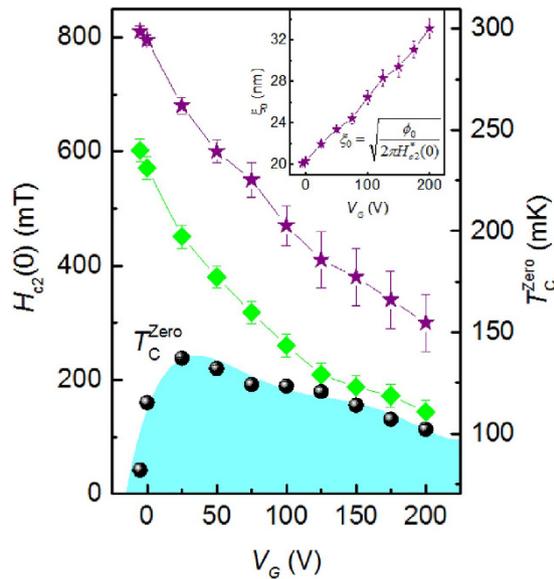
Figure 3 shows curves of  $H_{c2}^{50\%}(T)$  for different  $V_G$  from  $-5$  V up to 200 V. For all gate voltages,  $H_{c2}^{50\%}$  increases with temperature decrease. Curves of  $H_{c2}^{50\%}(T)$  shift into the region of higher values of  $H_{c2}^{50\%}-T$  for decreasing  $V_G$ . This enhancement occurs even for negative  $V_G$ , where a lower  $V_G$  induces a lower  $T_C^{Zero}$ . Moreover, the slope ( $dH_{c2}^{50\%}/dT$ ) of the  $H_{c2}^{50\%}(T)$  curve approaching  $H_{c2}^{50\%}(T) = 0$  systematically increases when  $V_G$  decreases. The overall observed tendency does not change, if we use in the analysis  $H_{c2}^{10\%}$  or  $H_{c2}^{peak}$  instead of  $H_{c2}^{50\%}$  (Fig. S2 a,b). According to Ginzburg-Landau (GL) theory, near  $T_c$  the upper critical field is a linear function of  $(T_c - T)$  and smoothly saturates when lowering the temperature. Our results suggest an anomalous unconventional behavior of the upper critical field vs. temperature, and it is no longer appropriate to describe this dependence using the GL theory. The  $H_{c2}^{10\%, 50\%, peak}(T = 0$  K) values obtained by linear extrapolation of e data at low temperature are increasing with decreasing  $V_G$ . The determination of  $H_{c2}$  at  $T = 0$  K lacks precision. However, if we estimate the relative  $H_{c2}$ -increase ( $\delta H_{c2}$ ) at a finite temperature (e.g. 60 mK) between the curves for  $V_G = -5$  V and  $V_G = 0$  V, a criterion closer to  $R_s = 0$  shows a lower value (i.e.  $\delta H_{c2}^{10\%} = 1.3\%$ , while  $\delta H_{c2}^{50\%} = 5.5\%$ ). This finds its understanding in the following: The emergence of  $R_s = 0$  is due to the global superconductivity. With increasing magnetic field, a finite resistance occurs, and, hence, global superconductivity disappears. However, local superconductivity still exists before the system recovers to normal state. Thus, it is reasonable that we observe a larger  $H_{c2}$  for a more negative  $V_G$ . This indicates that Cooper pair can persist up to a higher magnetic field than the upper critical field corresponding to global superconductivity.

**Superconductor-insulator transition.** The magnetic-field-induced superconductor-insulator transition(SIT)<sup>27</sup> shows a characteristic fan-shaped pattern of  $R_s(B)$  isotherms crossing at one point. For example, in Fig. 4a the SIT cross point for  $V_G = -5$  V is at 810 mT. The  $R_s(T)$  curves extracted from  $R_s(B)$  show a plateau for 810 mT (Fig. 4b). The plateau separates two regimes. Therefore, the magnetic field drives a continuous quantum phase transition from a superconducting 2DEG to a weakly insulating state. Further finite-size scaling analysis shows that the data can be collapsed onto a bi-value curve (Fig. 4a, inset). It results that the crossing point is a quantum critical point (QCP), at which the phase transition occurs. Literature often show magnetic-field-induced SIT for different 2D superconductors<sup>27,28</sup>, including for interfaces such as LAO/STO and (001) LTO/STO<sup>29,30</sup>.

As already noted,  $H_{c2}(T)$  for a fixed  $V_G$  depends on the criterion adopted for the  $H_{c2}$  determination in the case of a broad transition<sup>26,31</sup> and the  $H_{c2}(T = 0$  K) cannot be determined in a reliable manner. This situation questions the intrinsic nature of the  $H_{c2}$  - enhancement (for a lower  $V_G$ ) in the underdoped region. Due to this, here we use another method to directly determine the zero - temperature upper critical field,  $H_{c2}^*(T = 0$  K). This method is independent of the criterion applied to  $R_s(B)$  curves. At the QCP, taken as a transition point between superconducting and normal states of the 2DEG, the corresponding magnetic field is defined as  $H_{c2}^*(T = 0$  K). The



**Figure 4.** (a) SIM pattern: curves of  $R_s(B)$  at different temperatures for  $V = -5$  V. Note the crossing point at 810 mT that defines the quantum critical point (QCP) with  $(B_c = 810$  mT,  $R_c = 1297.54$   $\Omega$ ). The inset shows the bi-valued curve obtained by collapse of the data by finite-size scaling analysis. (b) Curves of  $R_s(T)$  at different magnetic fields  $B$  and for  $V_G = -5$  V. Dashed line shows a plateau corresponding to QCP. Continuous lines are guide for the eyes.



**Figure 5.** The  $V_G$  dependence of  $T_C^{\text{Zero}}$ ,  $H_{c2}^{50\%}$  ( $T = 0$  K) (green diamonds) and  $H_{c2}^*$  ( $T = 0$  K) (violet stars). The inset shows the  $V_G$  dependence of the coherence length  $\xi_0 = \sqrt{\Phi_0/2\pi H_{c2}^*}$  where  $\Phi_0$  is the quantum flux. Continuous lines are guide for the eyes.

$H_{c2}^*$  ( $T = 0$  K) curve as a function of  $V_G$  is plotted in Fig. 5. Although it is considered that this method does not give accurate values of  $H_{c2}^*$  ( $T = 0$  K)<sup>30</sup>, this barely affects our main results, the dependence on  $V_G$  of  $H_{c2}^*$  ( $T = 0$  K) being similar to that of  $H_{c2}^{50\%}$  ( $T = 0$  K) (Fig. 5). One reason for a non-precise determination of  $H_{c2}^*$  ( $T = 0$  K) vs.  $V_G$  is: when  $V_G \neq -5$  V, e.g., a  $V_G = 75$  V is used for the construction of the magnetic-field-induced SIT pattern, the crossing point of the  $R_s(B)$  isotherms transforms into a field domain centered at 0.55 T and extending over  $\pm 0.05$  T (Fig. S3a). In this case, the conventional power-law scaling behavior fails to describe the quantum criticality (Fig. S3b). Multiple quantum criticality was also found and reported for the (001) LTO/STO interface<sup>29</sup>. The phenomenon of multiple critical exponents suggests an unconventional critical behavior of SIT in the (110) LAO/STO interface, and it will be discussed elsewhere.

**Phase diagram.** The superconducting phase diagram of the (110) LAO/STO interface is presented in Fig. 5. As already addressed in the previous sections, the upper critical field  $H_{c2}$  independently of the criterion for its determination monotonically increases when  $V_G$  decreases, while  $T_C^{\text{Zero}}$  displays a dome-like curve with a maximum. In the inset to Fig. 5 is shown the GL coherence length  $\xi_0$  determined from  $H_{c2}$  as a function of  $V_G$ . The most striking anomalous result is enhancement of  $H_{c2}$  accompanied by the decrease of  $\xi_0$  for decreasing  $V_G$ , i.e. for the carrier depletion reflected by the dome-like curve in the underdoped region. Results indicate that the Cooper pairing potential is stronger in the underdoped region.

A systematic increase in  $H_{c2}$  with decreasing doping has been reported both in high- $T_c$  cuprates and iron-based superconductors<sup>31,32</sup>. This is usually considered as an evidence for the existence of a so-called ‘pseudogap’ state, in which the bosonic pairs form above  $T_c$  but cannot condensate into superconducting state due to dilution of pairs<sup>33</sup>. Recently, the planar tunneling spectroscopy study in 2DEG at a (001) LAO/STO interface has shown that the energy gap  $\Delta$  increases with charge carrier depletion in both underdoped and overdoped regions<sup>9</sup>. And, the coherence-peak-broadening parameter  $\Gamma$  derived from the Dynes fit, that is related to the strength of the superconducting pairing interaction, increases steeply with decreasing  $V_G$ . GuangLei Cheng *et al.*<sup>10</sup> recently reported that the Cooper pairs form at temperatures well above the superconducting transition temperature of the (001)LAO/STO superconducting system. In the experiments they used a superconducting single-electron transistor and they observed that pairs condensate at low magnetic fields and temperatures. The physical understanding of the processes at (110) LAO/STO interface is analogous to that of hole-doped cuprates<sup>31</sup>, namely, the pairing potential is stronger and the Ginzburg-Landau coherence length  $\xi_0$  decreases in the underdoped region as  $V_G$  decreases. The trend differs from that of superfluid density and superconducting transition temperature<sup>7,14</sup>. Namely, the superfluid density decreases with decreasing  $V_G$  providing that the phase fluctuation is important<sup>14,34,35</sup>. The observation of  $\Delta/\Gamma$  scaled with  $T_c$  in ref. 9 implies that the limited quasiparticle lifetime controls  $T_c$  effectively<sup>9</sup>, and the reduction in  $T_c$  versus  $\Delta$  was attributed to a competing order parameter or to a weak phase coherence. In addition, in LAO/STO system the spin-orbit coupling is non negligible and strongly depends on  $V_G$ <sup>36,37</sup>. Both conventional and unconventional pairing mechanisms have been considered to describe superconductivity in interfaces<sup>5,6,16,38</sup>. For example, the spin-orbit coupling<sup>36,37</sup> and the coexistence of superconductivity and ferromagnetism<sup>11–13</sup> may indicate formation of possible exotic superconducting states such as finite momentum Cooper pairing<sup>39,40</sup>. One has also to consider a different orbital reconstruction between (001) and (110) systems<sup>20,41</sup>. Superconducting properties and Rashba spin-orbit coupling can be largely tuned by controlling selective orbital occupancy in different crystal orientations<sup>20</sup>. For the underdoped region, it has been reported that a Lishiftz transition is observed at (001) interface<sup>42,43</sup>. The (110) system is expected to be characterized only by a  $3d_{xz}/d_{yz}$  filled electronic state; thus the superconducting properties of the (110) interface system can be substantially different from that of the (001) system.

## Conclusions

We systematically investigated the upper critical field as a function of gate voltage by ultralow temperature magnetoresistance measurements in superconducting 2DEG of a (110) LAO/STO interface. We found that upper critical field increases as the gate voltage decreases. Two independent methods to determine the upper critical field give a similar trend. This implies that the pairing potential is stronger in the underdoped region. This observation is similar to recent reports that consider a pseudogap-like behavior at the (001) LAO/STO interface. Our results for an interface with a different orientation contribute to understanding of the pairing mechanism of superconductivity at LAO/STO interface.

## Method

A five-unit-cell LaAlO<sub>3</sub> thin film was grown on the (110) SrTiO<sub>3</sub> substrate (500  $\mu\text{m}$  thickness) by pulsed laser deposition. Details were described in ref. 19. A metallic back gate was evaporated and attached to the rear of the substrate. Leakage current was low (below the maximum value of 5 nA at  $V_G = 200$  V). Standard four-terminal resistance measurements were made using wedge-bonding contacts. The sample was cooled in a dilution refrigerator with a base temperature of 10 mK. The measurement current is sufficiently low ( $\sim 50$  nA) to avoid sample heating at ultralow temperatures. To ensure the reversible behavior of the superconductivity, the gate voltage was ramped up to 200 V after cooling down. Perpendicular magnetic field  $B$  was applied to the sample (interface) surface and the field direction is the same for all measurements.

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## Author Contributions

J.C.N., G.P.G. and S.C.S. proposed and designed experiments. S.C.S., C.J.L. and Y.P.H. prepared the samples. S.C.S. performed the measurements with the assistance from B.B.C. and G.C. Results were analyzed by J.C.N., S.C.S., H.X.X. and X.X.W. The manuscript was written by S.C.S. and J.C.N. and discussed with C.M.X., R.F.D. and L.H. All authors discussed and contributed with comments regarding results and the manuscript.

## Additional Information

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